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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
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10/815,654

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Shunpei Yamazaki

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EXAMINER

KARIMY, MOHAMMAD TIMOR

ART UNIT

PAPER NUMBER

2894

MAIL DATE

DELIVERY MODE

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PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Office Action Summary	Application No. 10/815,654	Applicant(s) YAMAZAKI ET AL.	
	Examiner MOHAMMAD Timor KARIMY	Art Unit 2894	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 15 March 2010.
- 2a) ☒ This action is **FINAL**. 2b) ☐ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 48,52,56,61-63 and 66-71 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 48,52,56,61-63 and 66-71 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 02 April 2004 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☒ None of:
1. ☒ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. _____.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|---|---|
| 1) <input type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413) |
| 2) <input type="checkbox"/> Notice of Draftperson's Patent Drawing Review (PTO-948) | Paper No(s)/Mail Date. _____ |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO/SB/08) | 5) <input type="checkbox"/> Notice of Informal Patent Application |
| Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Product-by-Process Limitations

1. While not objectionable, the Office reminds Applicant that “product by process” limitations in claims drawn to structure are directed to the product, per se, no matter how actually made. *In re Hirao*, 190 USPQ 15 at 17 (footnote 3). See also, *In re Brown*, 173 USPQ 685; *In re Luck*, 177 USPQ 523; *In re Fessmann*, 180 USPQ 324; *In re Avery*, 186 USPQ 161; *In re Wethheim*, 191 USPQ 90 (209 USPQ 554 does not deal with this issue); *In re Marosi et al.*, 218 USPQ 289; and particularly *In re Thorpe*, 227 USPQ 964, all of which make it clear that it is the patentability of the final product per se which must be determined in a “product by process” claim, and not the patentability of the process, and that an old or obvious product produced by a new method is not patentable as a product, whether claimed in “product by process” claims or otherwise. Note that applicant has the burden of proof in such cases, as the above case law makes clear. Thus, no patentable weight will be given to those process steps which do not add structural limitations to the final product.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

3. Claims 48 and 61 are rejected under 35 U.S.C. 102(b) as being anticipated by Shimizu et al. (US Patent 5,085,973).

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Regarding claim 48, Shimizu teaches in figures 1-3 a semiconductor device comprising:

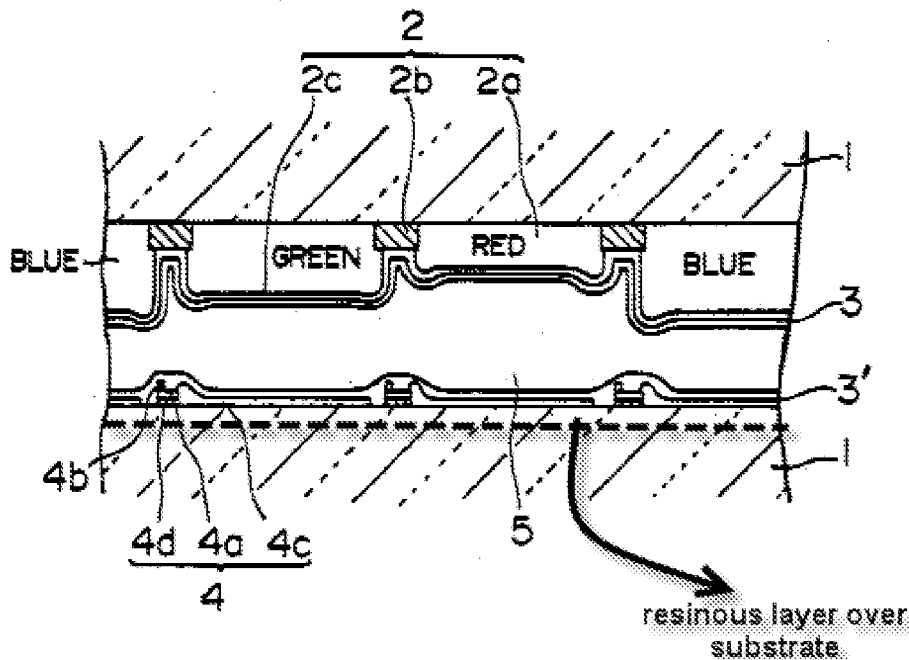
a pair of flexible insulating substrates 1 opposing to each other (Fig. 1);

a resinous layer (upper surface portion of substrate 1) formed over one of the pair of the flexible substrates 1 (see Fig. 1 below);

a thin film transistor 4 formed over the resinous layer, the thin film transistor having a semiconductor film comprising silicon (inherent, column 2 and line19); and

a layer 3 comprising resin covering the thin film transistor 4 (Fig. 1), wherein the semiconductor device is flexible (due to usage of resinous substrate, the device is flexible).

FIG. 1



Regarding claim 61, Shimizu teaches wherein the silicon is amorphous silicon (column 2 and line 19).

4. Claims 52, 56, 62-63, 66-68 and 70-71 are rejected under 35 U.S.C. 102(b) as anticipated by Shimizu or, in the alternative, under 35 U.S.C. 103(a) as obvious over Shimizu in view of Takahashi et al. (US Patent 5,574,292).

Regarding claim 52, Shimizu teaches in figures 1-3 a semiconductor device comprising:

a pair of flexible insulating substrates 1 opposing to each other (Fig. 1);
a resinous layer (upper surface portion of substrate 1) formed over one of the pair of the flexible insulating substrates 1 (see Fig. 1 above);
a thin film transistor (TFT) 4 formed over the resinous layer, the thin film transistor having a semiconductor film comprising silicon (inherent, column 2 and line19); and
a layer 3 comprising resin covering the thin film transistor 4 (Fig. 1), wherein the semiconductor device is flexible (due to usage of resinous substrate, the device is flexible).

Though Shimizu implicitly teaches crystalline silicon in the semiconductor film of the TFT; however, if it is determined that Shimizu has not disclosed said claimed dimension (i.e. crystalline silicon), then Takahashi teaches crystalline silicon in a semiconductor layer of a thin film transistor due to crystalline silicon's superior carrier mobility (column 1 and lines 29-33). Shimizu and Takahashi are analogous art (both deal with TFT devices). At the time of the invention, it would have been obvious to a person of ordinary skill in the art to use crystalline silicon in the TFT device if Shimizu for the benefit of enhanced carrier mobility. As such, Shimizu and Takahashi would have been combinable.

Regarding claim 62, though Shimizu implicitly teaches microcrystalline silicon in the semiconductor film of the TFT (see claim 48); however, if it is determined that Shimizu has not disclosed said claimed dimension (i.e. crystalline silicon), then Takahashi teaches crystalline silicon in a semiconductor layer of a thin film transistor

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due to crystalline silicon's superior carrier mobility (column 1 and lines 29-33). Shimizu and Takahashi are analogous art (both deal with TFT devices). At the time of the invention, it would have been obvious to a person of ordinary skill in the art to use crystalline silicon in the TFT device if Shimizu for the benefit of enhanced carrier mobility. As such, Shimizu and Takahashi would have been combinable.

Regarding claim 66, Shimizu teaches a semiconductor device according to claim 52, wherein the flexible insulating substrate comprises a plastic substrate (column 3 line 41).

Regarding claim 67, Shimizu teaches a semiconductor device according to claim 52, wherein the flexible insulating substrate comprises polyimide (polyimide is a type of resin).

Regarding claim 68, Shimizu teaches a semiconductor device according to claim 52, wherein the resinous layer comprises acrylic resin (Fig. 1).

Regarding claim 70, Shimizu teaches a semiconductor device according to claim 52, wherein the thin film transistor comprises an inverted-staggered TFT (Fig. 1).

Regarding claim 71, Shimizu teaches a semiconductor device according to claim 52, wherein the thin film transistor comprises a coplanar TFT (Fig. 1).

Regarding claim 56, Shimizu teaches in figures 1-3 a semiconductor device comprising:

a pair of flexible insulating substrates 1 opposing to each other (Fig. 1);

a resinous layer (upper surface portion of substrate 1) formed over one of the pair of the flexible insulating substrates 1 (see Fig. 1 above);

a thin film transistor (TFT) 4 formed over the resinous layer, and

a layer 3 comprising resin covering the thin film transistor 4 (Fig. 1), wherein the thin film transistor having a semiconductor film comprising silicon (inherent, column 2 and line19); and

the semiconductor device is flexible (due to usage of resinous substrate, the device is flexible).

Though Shimizu implicitly teaches crystalline silicon in the semiconductor film of the TFT; however, if it is determined that Shimizu has not disclosed said claimed dimension (i.e. crystalline silicon), then Takahashi teaches crystalline silicon in a semiconductor layer of a thin film transistor due to crystalline silicon's superior carrier mobility (column 1 and lines 29-33). Shimizu and Takahashi are analogous art (both deal with TFT devices). At the time of the invention, it would have been obvious to a person of ordinary skill in the art to use crystalline silicon in the TFT device if Shimizu for the benefit of enhanced carrier mobility. As such, Shimizu and Takahashi would have been combinable.

Also, it is important to note that the limitation "**wherein the crystalline silicon is formed by a laser irradiation**" is a product by process limitation and it does not structurally distinguish over the prior art.

Regarding claim 63, the limitation "**wherein the laser irradiation is conducted by using at least one selected from the group consisting of KrF excimer laser and**

XeCl laser" is a product by process limitation and it does not result to a structurally distinguishable product over the prior art.

Claim Rejections - 35 USC § 103

5. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

6. Claim 69 is rejected under 35 U.S.C. 103(a) as being unpatentable over Shimizu and Takahashi as applied to claim 52 above, and in further view of Takenouchi et al. (US Patent 5,427,961).

In regards to claim 69, Shimizu and Takahashi do not disclose the following:

a) the resinous layer comprises at least one selected from the group consisting of methyl esters of acrylic acid, ethyl esters of acrylic acid, butyl esters of acrylic acid, and 2-ethylhexyl esters of acrylic acid.

However, Takenouchi et al. ("Takenouchi") discloses a resinous layer that comprises at least one selected from the group consisting of methyl esters of acrylic acid, ethyl esters of acrylic acid, butyl esters of acrylic acid, and 2-ethylhexyl esters of acrylic acid (For Example: See Column 3 Lines 55-59). It would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the semiconductor of Brody to include a resinous layer that comprises at least one selected from the group consisting of methyl esters of acrylic acid, ethyl esters of acrylic acid, butyl esters of acrylic acid, and 2-ethylhexyl esters of acrylic acid as disclosed in

Takenouchi because it aids in preventing wear (For Example: See Column 4 Lines 47-50). Additionally, since Shimizu, Takahashi and Takenouchi are both from the same field of endeavor, the purpose disclosed by Takenouchi would have been recognized in the pertinent art of Shimizu and Takahashi.

Response to Arguments

7. Applicant's arguments with respect to claims 48, 52, 66, 61-63 and 66-71 have been considered but they are not found to be persuasive. Examiner submits that upper portion of the flexible substrate, as shown in Shimizu's Fig. 1 above, is interpreted as "a resinous layer". The line drawn and the label added by examiner has been included only to communicate properly examiner's application of prior art on the claims. Moreover, examiner maintains that the claims limitations remain broad and the prior arts, as applied above, meet the structural limitations of the claims. Lower portions of reference numeral 1 meets the feature "flexible insulating substrate" and upper portion of the reference numeral 1, as shown in Fig. 1 above, meets the feature "resinous layer". Shimizu expressly teaches in column 3, lines 40-42, wherein reference numeral 1 of Fig. 1 comprises resinous insulating material.

In view of the above, applicant's arguments are not persuasive.

Conclusion

8. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within

TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to MOHAMMAD Timor KARIMY whose telephone number is (571) 272-9006. The examiner can normally be reached on 8:30 AM - 5:00 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Kimberly Nguyen can be reached on 571-272-2402. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

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mtk

/Kimberly D Nguyen/
Supervisory Patent Examiner, Art Unit 2894